Synthesis and Characterization of Nano-pyramid Decorated ZnO Nanowires

Dinghao Tang*, Lawrence F. Allard** and Jingyue (Jimmy) Liu*

* Center for Nanoscience and Department of Physics and Astronomy, University of Missouri-St. Louis, One University Boulevard, St. Louis, Missouri 63121

** Materials Science and Technology Div., Oak Ridge National Laboratory, Oak Ridge, TN 37831

The wide-band gap (3.37 eV) semiconductor ZnO possesses unique physicochemical properties and has broad applications in electronics, optoelectronics, energy, sensing and catalysis. ZnO nanostructures such as wires, belts, rings, helixes and other types of structures have been recently synthesized [1]. The rich family of hierarchical ZnO nano/micro structures not only provides important applications but also provides a system for studying the fundamental nature of nucleation, growth and self-assembly of nanocomponents. Synthesis of surface-architectured nanostructures is critical to developing nanoscale sensors nanocatalysts. We report here our recent progress on synthesizing nano-pyramid decorated ZnO nanowires.

The ZnO nanostructures were grown by a standard thermal evaporation-condensation process [2]. To better control the surface morphology and the composition of the synthesized oxide nanostructures we used a mixture of oxygen (0-10%) and nitrogen or argon as the carrier gas. The morphology of the ZnO nanostructures was examined in a high-resolution field emission SEM, and their atomic structures were characterized in a JEOL 2200FS TEM/STEM equipped with a CEOS GmbH. aberration corrector on the probe-forming optics that provides a nominal probe diameter for STEM imaging of 0.07 nm.

Figure 1a shows a secondary-electron (SE) image of the synthesized ZnO nanowires decorated with nanoscale pyramids on its side surfaces. Detailed analysis showed that the diameters of the nanopyramid decorated nanowires range from 0.8 µm to 2 µm and their lengths range from 40 µm to about 0.5 mm. All the nano-pyramid decorated ZnO nanowires are extremely straight with growth directions along the ZnO [0001] direction. Figure 1b shows a high-resolution SE image of the nanoscale pyramids, showing that the base plane of the nano-pyramids is the ZnO (0001) basal pane. Measurements of many nano-pyramids, imaged in plan view, revealed that the angle between the basal plane and the side planes of the nano-pyramids is about 72°, which suggests that the side planes of the nano-pyramids are probably the ZnO {11-21} pyramid planes. Figure 1c shows a SE image of the growth end of a nano-pyramid decorated ZnO nanowire, clearly revealing the hexagonal shape of the nanowire and its flat basal plane. Figure 2a shows a STEM bright-field image of a truncated nano-pyramid and Figs. 2b and 2c show high-resolution STEM images of the base and side surfaces of the nano-pyramid, respectively. The corresponding optical diffractograms are shown in the insets. Analysis of the diffractograms showed that the base plane of the nanopyramids is the ZnO $\{0001\}$ plane and the side surfaces are composed of $\{11-21\}$ planes or $\{11-22\}$ planes. A detailed structural model of the observed nano-pyramids and their growth mechanisms will be discussed [3].

References

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Fig. 1. SEM images of nano-pyramid decorated ZnO nanowires.

Fig. 2. STEM BF image (a) and high-resolution images (b and c) of a truncated nano-pyramid show the atomic arrangement of the base and side surfaces of the nano-pyramids. The corresponding optical diffractograms are shown in the insets of images (b) and (c), respectively. The growth direction of the nanowire and the nano-pyramid is along the ZnO [001] direction.